



2N7002K

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	2Ω @ V _{GS} = 10V	380mA
000	3Ω @ V _{GS} = 5V	310mA

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- **Power Management Functions**
- Backlighting

N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

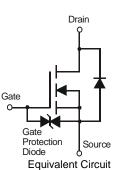
Mechanical Data

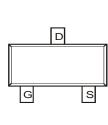
- Case: SOT23 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



Top View

SOT23





Top View

Ordering Information (Note 5)

	Part Number	Compliance	Case	Packaging			
	2N7002K-7 Standard		SOT23	3000/Tape & Reel			
	2N7002KQ-7	Automotive	SOT23	3000/Tape & Reel			
	2N7002K-13	Standard	SOT23	10000/Tape & Reel			
	2N7002KQ-13 Automotive SOT23 10000/Tape & Reel						
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

K7K	ΥM

K7K = Product Type Marking Code YM or $\overline{Y}M$ = Date Code Marking

- Y or \overline{Y} = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key 2006 2018 2019 2020 2021 2022 2023 2024 2025 2026 2027 Year Code G н Μ Ν 0 т F J Κ L Мау Mar Jun Aug Nov Month Jan Feb Apr Jul Sep Oct Dec Code 0 D 2 3 5 6 7 8 9 Ν 4



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
		T _A = +25°C T _A = +70°C	ID	380 300	mA
Continuous Drain Current (Note 7) V _{GS} = 10V	t<5s	T _A = +25°C T _A = +70°C	I _D	430 340	mA
	Steady State	T _A = +25°C T _A = +70°C	ID	310 240	mA
Continuous Drain Current (Note 7) V _{GS} = 5V t<5s		T _A = +25°C T _A = +70°C	ID	350 270	mA
Maximum Continuous Body Diode Forward Current (Note 7)			ls	0.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) (Note 7)			I _{DM}	1.2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	370	mW
Thermal Registeries, Junction to Ambient (Note 6)	Steady State	D	357	°C/W
Thermal Resistance, Junction to Ambient (Note 6)		R _{0JA}	292	C/W
Total Power Dissipation (Note 7)		PD	540	mW
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	D	240	
mermai Resistance, Junction to Ambient (Note 7)	t<5s	R _{θJA}	197	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	91	
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Cymbol		ijΡ	max	Unit	
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	Igss		—	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	1.0	1.6	2.5	V	$V_{DS} = 10V, I_D = 1mA$
Static Drain-Source On-Resistance			-	2.0	Ω	$V_{GS} = 10V, I_D = 0.5A$
	R _{DS(ON)}	_	—	3.0	12	$V_{GS} = 5V, I_D = 0.05A$
Forward Transfer Admittance	Y _{fs}	80		_	ms	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	V _{SD}	_	0.75	1.1	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 9)					-	
Input Capacitance	Ciss		30	50	pF	
Output Capacitance	Coss		4.2	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.9	5.0	pF	1 - 1.00012
Gate Resistance	Rg	_	133	—	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge	Qg	_	0.3	_	nC	
Gate-Source Charge	Qgs		0.2	-	nC	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA
Gate-Drain Charge	Q _{gd}	_	0.08	_	nC	ID = 230IIIA
Turn-On Delay Time	t _{D(ON)}		3.9		ns	
Turn-On Rise Time	t _R		3.4	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	_	15.7	_	ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t _F		9.9	_	ns	

Notes:

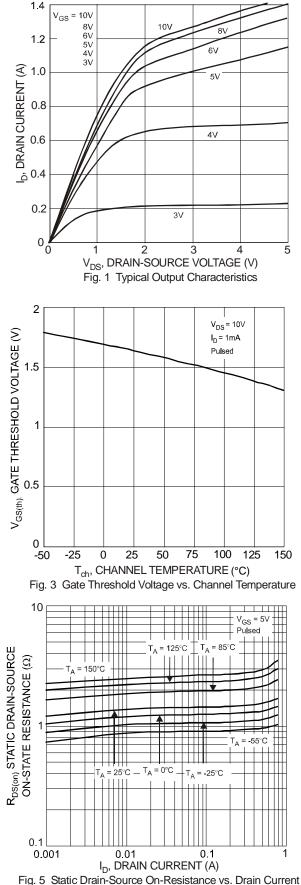
Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.

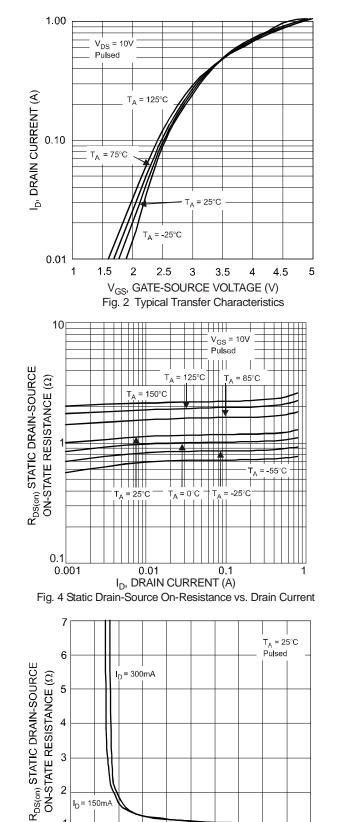
8. Short duration pulse test used to minimize self-heating effect.

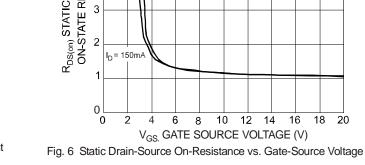
9. Guaranteed by design. Not subject to product testing.



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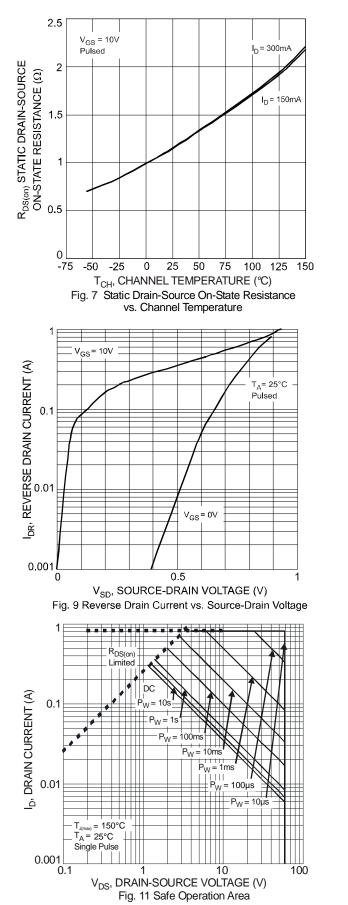


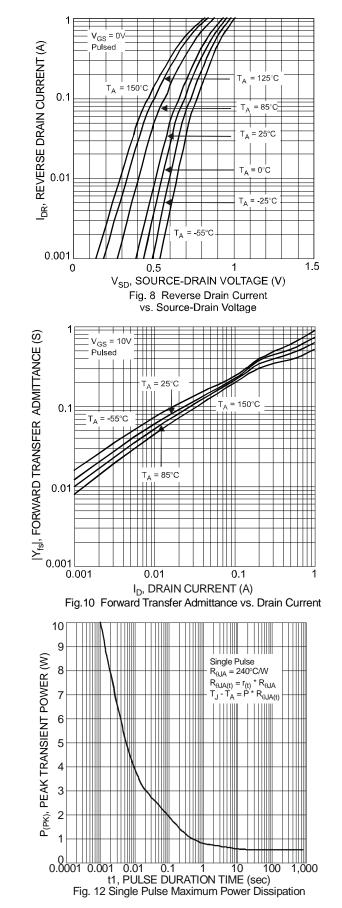


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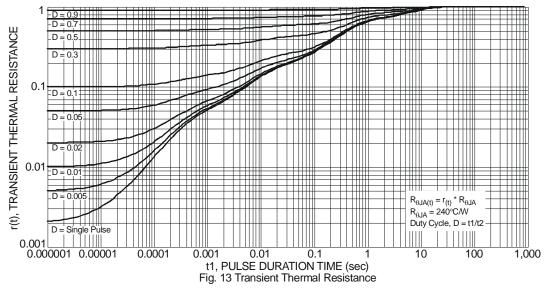






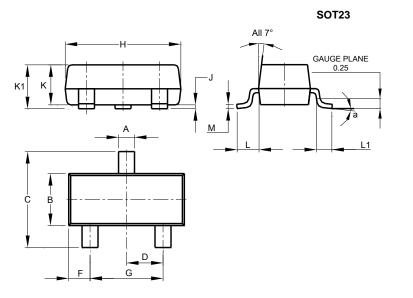


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Package Outline Dimensions

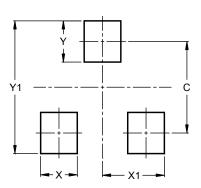
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
Μ	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)	
С	2.0	
Х	0.8	
X1	1.35	
Y	0.9	
Y1	2.9	

SOT23



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